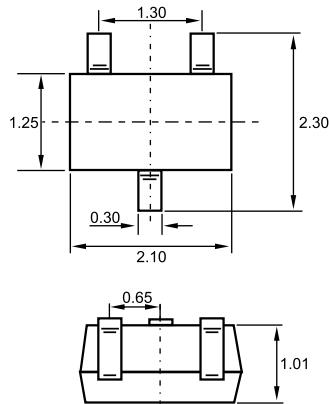


Features

- ◊ For types of packaging are available.
- ◊ High speed switching.
- ◊ Suitable for high packing density layout.
- ◊ High reliability.

SOT-323



Dimensions in inches and (millimeters)

Applications

- ◊ For general purpose switching applications.

Ordering Information

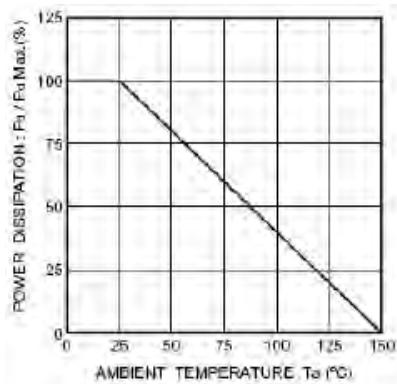
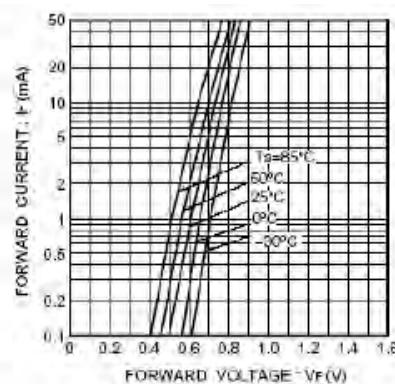
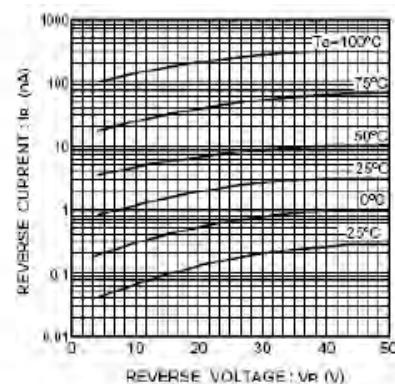
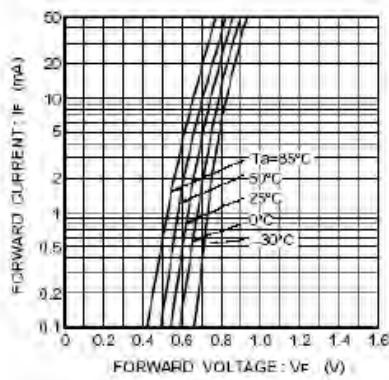
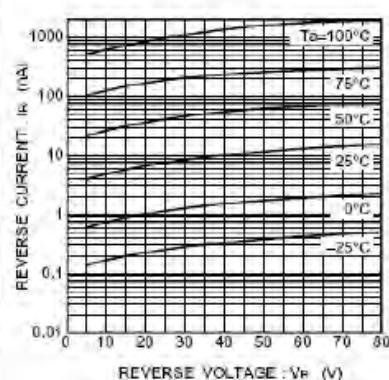
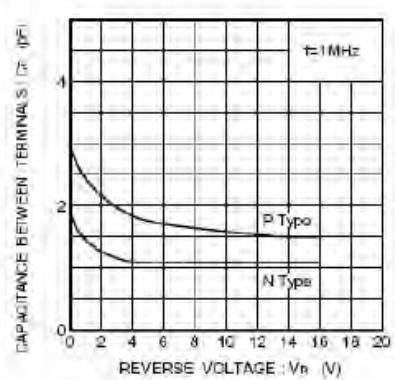
Type No.	Marking	Package Code
DAN202U	N	SOT-323

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	Limits	Unit
Non-Repetitive Peak reverse voltage	V _{RM}	80	V
Diode reverse voltage	V _R	80	V
Forward continuous Current (peak)	I _F	300	mA
Average forward current	I _O	100	mA
Power Dissipation	P _d	200	mW
Junction temperature	T _j	150	°C
Storage temperature range	T _{stg}	-65+150	°C

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	$V_{(BR)R}$	$I_R = 100\mu A$	80		V
Reverse voltage leakage current	I_R	$V_R = 70V$		0.1	μA
Forward voltage	V_F	$I_F = 100mA$		1.2	V
Diode capacitance	C_D	$V_R = 6V$ f=1MHz		3.5	pF
Reverse recovery time	t_{rr}	$V_R = 6V, I_F = 5mA$		4	nS

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Fig.1 Power attenuation curve

Fig.2 Forward characteristics (P Type)

Fig.3 Reverse characteristics (P Type)

Fig.4 Forward characteristics (N Type)

Fig.5 Reverse characteristics (N Type)

Fig.6 Capacitance between terminals characteristics